







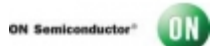

	<h2 style="color: red;">H11AA2VM</h2> <p>Hersteller-Teilenummer: H11AA2VM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: OPTOISO 7.5KV TRANS W/BASE 6DIP</p> <p>Datenblätter:  H11AA2VM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
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Spezifikationen

Teilenummer	H11AA2VM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	OPTOISO 7.5KV TRANS W/BASE 6DIP
Kategorie	Isolatoren > Optoisolatoren - Transistor, Photovoltaik-
Teilstatus	2000 pcs Stock
Serie	-
Eingabetyp	AC, DC
Betriebstemperatur	-40°C ~ 100°C
Befestigungsart	Through Hole
Ausgabebetyp	Transistor with Base
Anzahl der Kanäle	1
Verpackung / Gehäuse	6-DIP (0.300", 7.62mm)
Supplier Device-Gehäuse	6-DIP
Strom - Ausgang / Kanal	50mA
Spannung - Isolation	7500Vpk
Aufstieg / Fallzeit (Typ)	-
Spannung - Ausgabe (max)	30V
Spannung - Vorwärts (Vf) (Typ)	1.17V
Strom - DC Vorwärts (If) (Max)	60mA
Gleichstrom-Übertragungsverhältnis (min)	10% @ 10mA
Stromübertragungsverhältnis (max)	-
Ein- / Ausschaltzeit (Typ)	-
VCE Sättigung (max)	400mV
Verpackung	Tube

















H11AA2VM ist neu im Original, Suche H11AA2VM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie H11AA2VM Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage H11AA2VM: Info@Y-IC.com

Sie können auch interessiert sein:

 H11AA2W AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANS W/BASE 6DIP	 H11AA2VM Fairchild/ON Semiconductor OPTOISO 7.5KV TRANS W/BASE 6DIP	 H11AA2TM AMI Semiconductor / ON Semiconductor OPTOISO 7.5KV TRANS W/BASE 6DIP	 H11AA2W Fairchild/ON Semiconductor OPTOISO 5.3KV TRANS W/BASE 6DIP
 H11AA2SVM Fairchild/ON Semiconductor OPTOISO 7.5KV TRANS W/BASE 6SMD	 H11AA2VM AMI Semiconductor / ON Semiconductor OPTOISO 7.5KV TRANS W/BASE 6DIP	 H11AA2VM AMI Semiconductor / ON Semiconductor OPTOISO 7.5KV TRANS W/BASE 6DIP	 H11AA3 Fairchild/ON Semiconductor OPTOISO 5.3KV TRANS W/BASE 6DIP

heiße Teile

Mehr

 H11A817C300	 H11A817C3SD	 H11A817C3SD	 H11A817CSD	 H11A817CSD
 H11A817CW	 H11A817CW	 H11A817SD	 H11A817SD	 H11A817X
 H11A817X-5627W	 H11A817X-5632	 H11AA1-X007T	 H11AA1-X007T	 H11AA1SR2M
 H11AA1SR2M	 H11AA1TM	 H11AA1TM	 H11AA1TVM	 H11AA1TVM
 H11AA2SM	 H11AA2SM	 H11AA2SR2M	 H11AA2SR2M	 H11AA2VM
 H11AA3SD	 H11AA3SD	 H11AA3SM	 H11AA3SM	 H11AA3SR2M
 H11AA3SR2M	 H11AA3SR2VM	 H11AA3SR2VM	 H11AA3VM	 H11AA3VM
 H11AA4SM	 H11AA4SM	 H11AA4SR2M	 H11AA4SR2M	 H11AA4SR2VM
 H11AA4SR2VM	 H11AA4SVM	 H11AA4SVM	 H11AA4TVM	 H11AA4TVM
 H11AA4VM	 H11AA4VM	 H11AA814	 H11AA814	 H11AA814.3SD

Contact us: Info@Y-IC.com

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